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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Wireless Components

ASK/FSK 915MHz Single Conversion Receiver TDA 5212 Version 1.3

Specification December 2006

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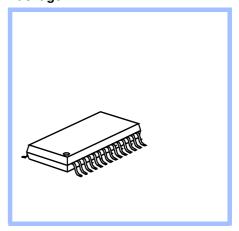


Product Info

General Description

The IC is a very low power consumption single chip FSK/ASK Superheterodyne Receiver (SHR) for the receive frequency range between 902 and 928 MHz that is pin compatible to the ASK Receiver TDA5202. The IC offers a high level of integration and needs only a few external components. The device contains a low noise amplifier (LNA), a double balanced mixer, a fully integrated VCO, a PLL synthesiser, a crystal oscillator, a limiter with RSSI generator, a PLL FSK demodulator, a data filter, a data comparator (slicer) and a peak detector. Additionally there is a power down feature to save battery life.

Package



Features

- Low supply current (I_S = 5.4 mA typ. in FSK mode, I_S = 4.8 mA typ. in ASK mode)
- Supply voltage range 5 V ±10%
- Power down mode with very low supply current (90 nA typ.)
- FSK and ASK demodulation capability
- Fully integrated VCO and PLL Synthesiser
- ASK sensitivity better than
 -109 dBm over specified temperature range (- 40 to +85°C)

- Receive frequency range 902 to 928 MHz
- Limiter with RSSI generation, operating at 10.7 MHz
- Selectable reference frequency
- 2nd order low pass data filter with external capacitors
- Data slicer with self-adjusting threshold
- FSK sensitivity better than
 -102 dBm over specified temperature range (- 40 to +85°C)

Application

- Keyless Entry Systems
- Remote Control Systems
- Low Bitrate ISM-band Communication Systems

Ordering Information

Туре	Ordering Code	Package	
TDA 5212	SP000013430	PG-TSSOP-28	
samples available			

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Product Description

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2.1 Overview

The IC is a very low power consumption single chip FSK/ASK Superheterodyne Receiver (SHR) for receive frequencies between 902 and 928 MHz that is pin compatible to the ASK Receiver TDA5202. The IC offers a high level of integration and needs only a few external components. The device contains a low noise amplifier (LNA), a double balanced mixer, a fully integrated VCO, a PLL synthesiser, a crystal oscillator, a limiter with RSSI generator, a PLL FSK demodulator, a data filter, a data comparator (slicer) and a peak detector. Additionally there is a power down feature to save battery life.

2.2 Application

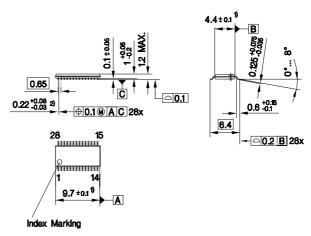
- Keyless Entry Systems
- Remote Control Systems
- Low Bitrate ISM-band Communication Systems

2.3 Features

- Low supply current (I_s = 5.4 mA typ.FSK mode, 4.8 mA typ. ASK mode)
- Supply voltage range 5V ±10%
- Power down mode with very low supply current (90nA typ.)
- FSK and ASK demodulation capability
- Fully integrated VCO and PLL Synthesiser
- RF input sensitivity ASK -112dBm typ. at 25°C, better than -109dBm over complete specified operating temperature range (-40 to +85°C)
- RF input sensitivity FSK -105dBm typ. at 25°C, better than -102dBm over complete specified operating temperature range (-40 to +85°C)
- Receive frequency range between 902 and 928 MHz
- Selectable reference frequency
- Limiter with RSSI generation, operating at 10.7MHz
- 2nd order low pass data filter with external capacitors
- Data slicer with self-adjusting threshold

Product Description

2.4 Package Outlines



- 1) Does not include plastic or metal protrusion of 0.15 max. per side
- 2) Does not include dambar protrusion

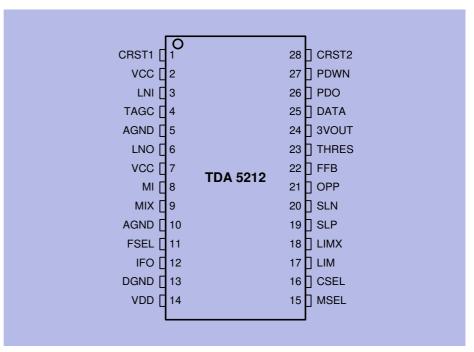
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Figure 2-1 PG-TSSOP-28 package outlines

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3.1 Pin Configuration



Pin_Configuration_5212_V1.0.wmf

Figure 3-1 IC Pin Configuration



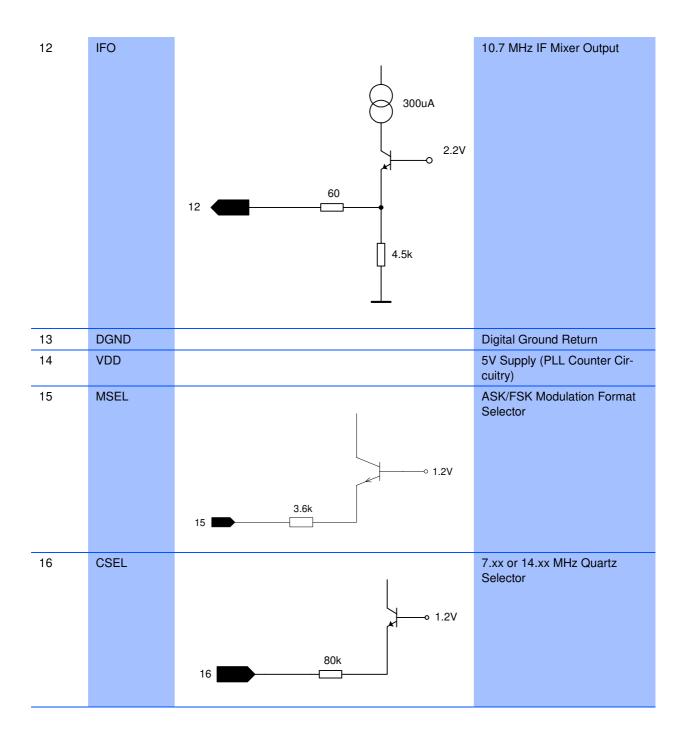
3.2 Pin Definition and Function

Table 3-1 Pin Definition and Function			
Pin No.	Symbol	Equivalent I/O-Schematic	Function
1	CRST1	4.15V 50uA	External Crystal Connector 1
2	VCC		5V Supply
3	LNI	57uA 3 500uA	LNA Input



4	TAGC	4.3V	AGC Time Constant Control
		4 1k 1.5uA	
		 1.7V	
5	AGND		Analogue Ground Return
6	LNO	5V 	LNA Output
		1k	
		h-	
7	VCC		5V Supply
8	MI	1.7V	Mixer Input
9	MIX	8	Complementary Mixer Input
		400uA	
10	AGND		Analogue Ground Return
11	BUF		Mixer Buffer Ground







17	LIM		Limiter Input
18	LIMX	2.4V 115k 1330 75uA	Complementary Limiter Input
		15k	
19	SLP	19	Data Slicer Positive Input
20	SLN	5uA	Data Slicer Negative Input



21	OPP	OpAmp Noninverting Input 5uA
		21
22	FFB	Data Filter Feedback Pin
		5uA
		22 100k
23	THRES	AGC Threshold Input
		5uA
		23 10k
24	3VOUT	3V Reference Output
		24 20kΩ 3.1V



25	DATA		Data Output
		25 ————————————————————————————————————	
26	PDO	260	Peak Detector Output
27	PDWN	220k	Power Down Input
28	CRST2	4.15V 50uA	External Crystal Connector 2



3.3 Functional Block Diagram

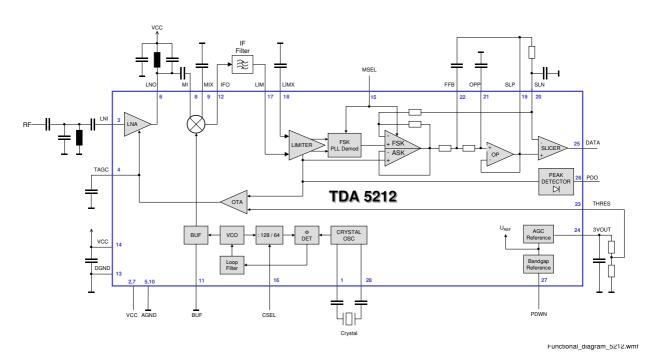


Figure 3-2 Main Block Diagram



3.4 Functional Blocks

3.4.1 Low Noise Amplifier (LNA)

The LNA is an on-chip cascode amplifier with a voltage gain of 15 to 20dB. The gain figure is determined by the external matching networks situated ahead of LNA and between the LNA output LNO (Pin 6) and the Mixer Inputs MI and MIX (Pins 8 and 9). The noise figure of the LNA is approximately 2dB, the current consumption is 500µA. The gain can be reduced by approximately 18dB. The switching point of this AGC action can be determined externally by applying a threshold voltage at the **THRES** pin (Pin 23). This voltage is compared internally with the received signal (RSSI) level generated by the limiter circuitry. In case that the RSSI level is higher than the threshold voltage the LNA gain is reduced and vice versa. The threshold voltage can be generated by attaching a voltage divider between the **3VOUT** pin (Pin 24) which provides a temperature stable 3V output generated from the internal bandgap voltage and the THRES pin as described in Section 4.1. The time constant of the AGC action can be determined by connecting a capacitor to the TAGC pin (Pin 4) and should be chosen along with the appropriate threshold voltage according to the intended operating case and interference scenario to be expected during operation. The optimum choice of AGC time constant and the threshold voltage is described in Section 4.1.

3.4.2 Mixer

The Double Balanced Mixer downconverts the input frequency (RF) in the range of 902 to 928 MHz to the intermediate frequency (IF) at 10.7MHz with a voltage gain of approximately 18 dB. A low pass filter with a corner frequency of 20MHz is built on chip in order to suppress RF signals to appear at the IF output (\mbox{IFO} pin). The IF output is internally consisting of an emitter follower that has a source impedance of approximately 330Ω to facilitate interfacing the pin directly to a standard 10.7MHz ceramic filter without additional matching circuitry.

3.4.3 PLL Synthesizer

The Phase Locked Loop synthesiser consists of a VCO, an asynchronous divider chain, a phase detector with charge pump and a loop filter and is fully implemented on-chip. The VCO is including spiral inductors and varactor diodes. The oscillator signal is fed both to the synthesiser divider chain and to the downconverting mixer via a buffer amplifier. The **BUF** pin (Pin 11) has to be tied to ground. No additional components are necessary. The loop filter is also realised fully on-chip.

Using high side injection of the local oscillator (L0) for receiving frequencies below 921MHz and low side injection for frequencies above 921MHz, the receiving frequency band of 902 to 928MHz can be covered due to the L0 fre-



quency band of 910 to 932MHz. But please note that using high side injetion of the L0 yields a sign inversion of the demodulated data signal in case of FSK. See also Section 4.4.

3.4.4 Crystal Oscillator

The on-chip crystal oscillator circuitry allows for utilisation of quartzes both in the 7 and 14MHz range as the overall division ratio of the PLL can be switched between 64 and 128 via the **CSEL** (Pin 16) pin according to the following table.

Table 3-2 CSEL Pin Operating States		
CSEL	Crystal Frequency	
Open	7.xx MHz	
Shorted to ground	14.xx MHz	

The calculation of the value of the necessary quartz load capacitance is shown in Section 4.3, the quartz frequency calculation is expained in Section 4.4.

3.4.5 Limiter

The Limiter is an AC coupled multistage amplifier with a cumulative gain of approximately 80dB that has a bandpass-characteristic centred around 10.7MHz. It has an input impedance of 330Ω to allow for easy interfacing to a 10.7MHz ceramic IF filter. The limiter circuit acts as a Receive Signal Strength Indicator (RSSI) generator which produces a DC voltage that is directly proportional to the input signal level as can be seen in Figure 4.2. This signal is used to demodulate the ASK receive signal in the subsequent baseband circuitry and to turn down the LNA gain by approximately 18dB in case the input signal strength is too strong as described in Section 3.4.1 and Section 4.1.

3.4.6 FSK Demodulator

To demodulate frequency shift keyed (FSK) signals a PLL circuit is used that is contained fully on chip. The Limiter output differential signal is fed to the linear phase detector as is the output of the 10.7MHz center frequency VCO. The demodulator gain is typically $200\mu\text{V/kHz}.$ The passive loop filter output that is comprised fully on chip is fed to both the VCO and the modulation format switch.This signal is representing the demodulated signal. This switch is actually a switchable amplifier with an AC gain of 11 that is controlled by the **MSEL**

pin (Pin 15) as shown in the following table. This gain was chosen to facilitate detection in the subsequent circuits.

Table 3-3 MSEL Pin Operating States	
MSEL	Modulation Format
Open	ASK
Shorted to ground	FSK

The DC gain is 1 in order not to saturate the subsequent Data Filter wih the DC offset produced by the demodulator in case of large frequency offsets of the IF signal. The resulting frequency characteristic and details on the principle of operation of the switch are described in Section 4.6. The demodulator circuit is switched off in case of reception of ASK signals.

3.4.7 Data Filter

The data filter comprises an OP-Amp with a bandwidth of 100kHz used as a voltage follower and two $100k\Omega$ on-chip resistors. Along with two external capacitors a 2nd order Sallen-Key low pass filter is formed. The selection of the capacitor values is described in Section 4.2.

3.4.8 Data Slicer

The data slicer is a fast comparator with a bandwidth of 100 kHz. This allows for a maximum receive data rate of approximately 120kBaud. The maximum achievable data rate also depends on the IF Filter bandwidth and the local oscillator tolerance values. Both inputs are accessible. The output delivers a digital data signal (CMOS-like levels) for the detector. The self-adjusting threshold on pin 20 its generated by RC-term or peak detector depending on the baseband coding scheme. The data slicer threshold generation alternatives are described in more detail in Section 4.5.

3.4.9 Peak Detector

The peak detector generates a DC voltage which is proportional to the peak value of the receive data signal. An external RC network is necessary. The input is connected to the output of the RSSI-output of the Limiter, the output is connected to the **PDO** pin (Pin 26). This output can be used as an indicator for the received signal strength to use in wake-up circuits and as a reference for the data slicer in ASK mode. Note that the RSSI level is also output in case of FSK mode.



3.4.10 Bandgap Reference Circuitry

A Bandgap Reference Circuit provides a temperature stable reference voltage for the device. A power down mode is available to switch off all subcircuits which is controlled by the **PWDN** pin (Pin 27) as shown in the following table. The supply current drawn in this case is typically 90nA.

Table 3-4 PDWN Pin Operating States	
PDWN	Operating State
Open or tied to ground	Powerdown Mode
Tied to Vs	Receiver On

4 Applications

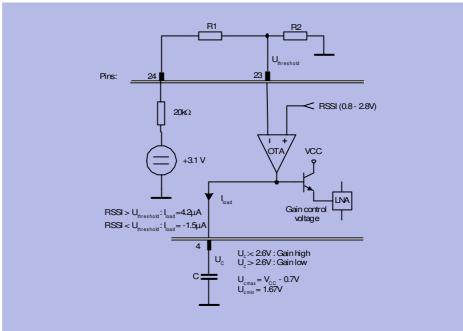
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4.1 Choice of LNA Threshold Voltage and Time Constant

In the following figure the internal circuitry of the LNA automatic gain control is shown.



LNA_autom.wmf

Figure 4-1 LNA Automatic Gain Control Circuitry

The LNA automatic gain control circuitry consists of an operational transimpedance amplifier that is used to compare the received signal strength signal (RSSI) generated by the Limiter with an externally provided threshold voltage U_{thres} . As shown in the following figure the threshold voltage can have any value between approximately 0.8 and 2.8V to provide a switching point within the receive signal dynamic range.

This voltage U_{thres} is applied to the **THRES** pin (Pin 23) The threshold voltage can be generated by attaching a voltage divider between the **3VOUT** pin (i.e. Pin 24) which provides a temperature stable 3V output generated from the internal bandgap voltage and the **THRES** pin. If the RSSI level generated by the Limiter is higher than U_{thres} , the OTA generates a positive current I_{load} . This yields a voltage rise on the **TAGC** pin (Pin 4). Otherwise, the OTA generates a negative current. These currents do not have the same values in order to achieve a fast-attack and slow-release action of the AGC and are used to charge an external capacitor which finally generates the LNA gain control voltage.



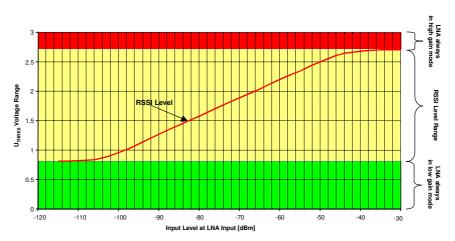


Figure 4-2 RSSI Level and Permissive AGC Threshold Levels

RSSI-AGC.wmf

The switching point should be chosen according to the intended operating scenario. The determination of the optimum point is described in the accompanying Application Note, a threshold voltage level of 1.8V is apparently a viable choice. It should be noted that the output of the **3VOUT** pin is capable of driving up to $50\mu\text{A}$, but that the **THRES** pin input current is only in the region of 40nA. As the current drawn out of the **3VOUT** pin is directly related to the receiver power consumption, the power divider resistors should have high impedance values. The sum of R1 and R2 has to be $600k\Omega$ in order to yield 3V at the **3VOUT** pin. R1 can thus be chosen as $240k\Omega$, R2 as $360k\Omega$ to yield an overall **3VOUT** output current of $5\mu\text{A}^1$ and a threshold voltage of 1.8V

Note: If the LNA gain shall be kept in either high or low gain mode this has to be accomplished by tying the **THRES** pin to a fixed voltage. In order to achieve high gain mode operation, a voltage higher than 2.8V shall be applied to the **THRES** pin, such as a short to the **3VOLT** pin. In order to achieve low gain mode operation a voltage lower than 0.7V shall be applied to the **THRES**, such as a short to ground.

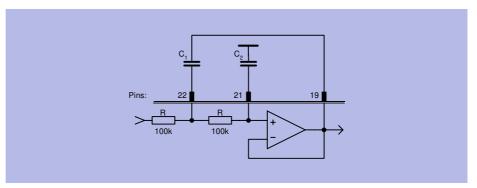
As stated above the capacitor connected to the **TAGC** pin is generating the gain control voltage of the LNA due to the charging and discharging currents of the OTA and thus is also responsible for the AGC time constant. As the charging and discharging currents are not equal two different time constants will result. The time constant corresponding to the charging process of the capacitor shall be chosen according to the data rate. According to measurements performed at Infineon the capacitor value should be greater than 47nF.

^{1.} note the $20 k\Omega$ resistor in series with the 3.1V internal voltage source



4.2 Data Filter Design

Utilising the on-board voltage follower and the two $100k\Omega$ on-chip resistors a 2nd order Sallen-Key low pass data filter can be constructed by adding 2 external capacitors between pins 19 (SLP) and 22 (FFB) and to pin 21 (OPP) as depicted in the following figure and described in the following formulas 1 .



Filter Design.wmf

Figure 4-3 Data Filter Design

$$C1 = \frac{2Q\sqrt{b}}{R2\Pi f_{3dB}} \qquad C2 = \frac{\sqrt{b}}{4QR\Pi f_{3dB}}$$

with

$$Q = \frac{\sqrt{b}}{a}$$

the quality factor of the poles

where

in case of a Bessel filter a = 1.3617, b = 0.618

and thus Q = 0.577

and in case of a Butterworth filter a = 1.141, b = 1 and thus Q = 0.71

Example: Butterworth filter with $f_{3dB} = 5kHz$ and $R = 100k\Omega$:

$$C_1 = 450pF, C_2 = 225pF$$

^{1.} taken from Tietze/Schenk: Halbleiterschaltungstechnik, Springer Berlin, 1999